



MR3029-81

JFW

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

Applicant : Shangir Gwo :
Serial No. : 10/714,649 : Art Unit #2818
Filed : 18 November 2003 : Examiner: D. A. Le
Title : METHOD FOR GROWING GROUP-III
NITRIDE SEMICONDUCTOR
HETEROSTRUCTURE ON SILICON
SUBSTRATE

RESPONSE TO RESTRICTION REQUIREMENT
AND AMENDMENT

Mail Stop NO FEE
Honorable Commissioner for Patents
P.O. Box 1450
Alexandria, VA 22313-1450

Sir:

Applicant, by the undersigned attorney hereby responds to the outstanding
Official Action dated 9 March 2005 which is a Restriction Requirement. Please
amend the above-referenced patent application as follows:

Amendments to the Claims begin on page 2 of this paper.

Remarks/Arguments begin on page 8 of this paper.